

DESCRIPTION

The SE/NE5119 is a high-speed 8-bit digital to analog converter subsystem on one monolithic chip. The data inputs have input latches, controlled by a latch enable pin. The data and latch enable inputs are ultralow loading for easy interfacing with all logic systems. The latches appear transparent when the LE input is in the low state. When LE goes high, the input data present at the moment of transition is latched and retained until LE again goes low. This feature allows easy compatibility with most microprocessors.

The chip also comprises a stable voltage reference (5V nominal). The voltage reference may be externally trimmed with a potentiometer for easy adjustment of full scale, while maintaining a low temperature coefficient.

The output has high voltage compliance increasing versatility.

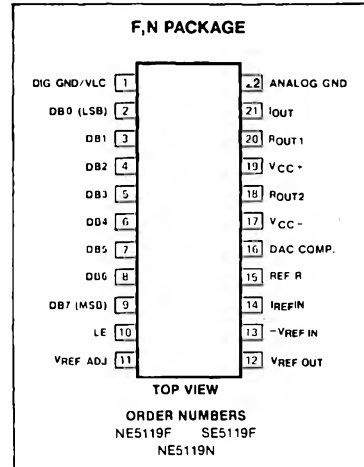
FEATURES

- 8-bit resolution
- Input latches
- Low-loading data inputs
- On-chip voltage reference
- Fast settling output current—200ns
- Accurate to $\pm 1/4$ LSB (.1%)
- Monotonic to 8 bits
- Reference short-circuit protected
- Compatible with 8086, 6800 and many other μ P's

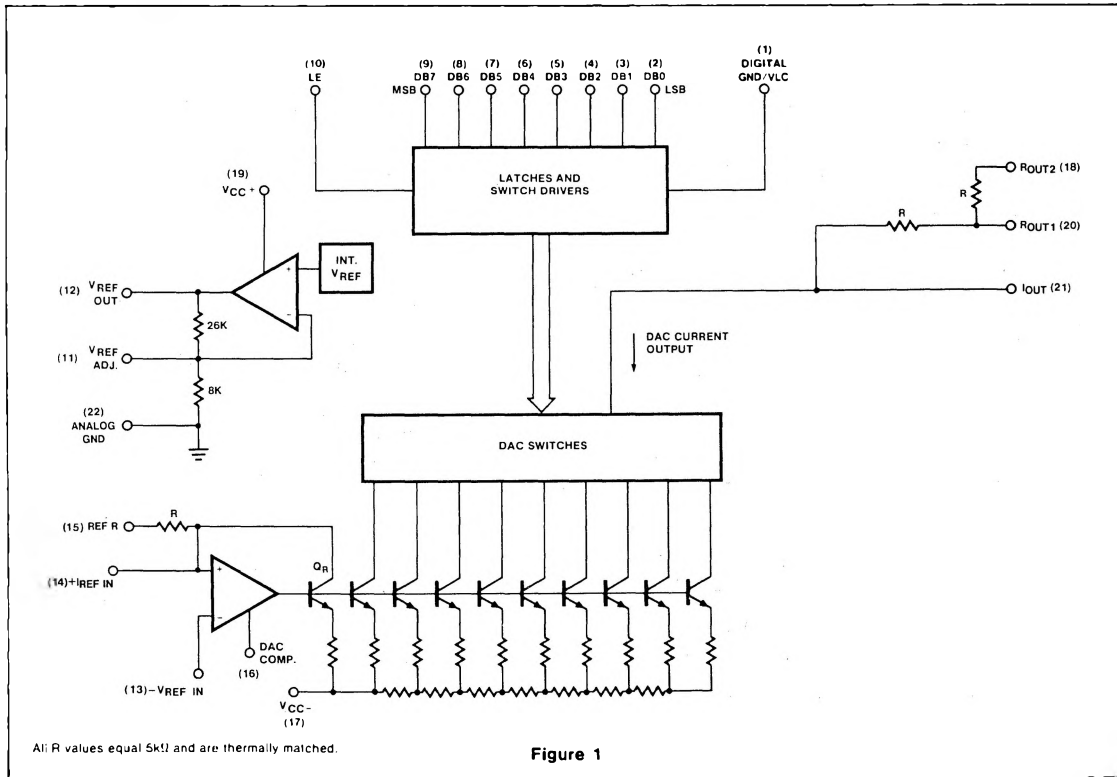
APPLICATIONS

- Precision 8-bit D/A converters
- A/D converters
- Programmable power supplies
- Test equipment
- Measuring instruments
- Analog-digital multiplication
- CRT display drivers
- High-speed modems

PIN CONFIGURATION



BLOCK DIAGRAM



8-BIT μ P-COMPATIBLE D/A CONVERTER—CURRENT OUTPUT

SE/NE5119

ABSOLUTE MAXIMUM RATINGS

PARAMETER	RATING	UNIT	
V _{CC+}	Positive supply voltage	18	V
V _{CC-}	Negative supply voltage	-18	V
V _{IN}	Logic input voltage	0 to 18	V
V _{REFIN}	Voltage at R _{REF} input	12	V
V _{REFADJ}	Voltage at V _{REF} adjust	0 to V _{REF}	V
V _{SUM}	Voltage at sum node	12	V
I _{REFSC}	Short-circuit current to ground at V _{REF} OUT	Continuous	
I _{REFIN}	Reference input current (Pin 14)	3	mA
P _D	Power dissipation*		
	-N package	800	mW
	-F package	1000	mW
T _A	Operating temperature range		
	SE5119	-55 to +125	°C
	NE5119	0 to +70	°C
T _{STG}	Storage temperature range	-65 to +150	°C
T _{SOLD}	Lead soldering temperature (10 seconds)	300	°C

*NOTES

For N package, derate at 120°C/W above 35°C
 For F package, derate at 75°C/W above 75°C

DC ELECTRICAL CHARACTERISTICS V_{CC+} = +15V, V_{CC-} = -15V, SE5119, -55°C ≤ T_A ≤ 125°C, NE5119, 0°C ≤ T_A ≤ 70°C unless otherwise specified.
 Typical values are specified at 25°C

PARAMETER	TEST CONDITIONS	SE5119			NE5119			UNIT		
		Min	Typ	Max	Min	Typ	Max			
Resolution		8	8	8	8	8	8	Bits		
Monotonicity		8	8	8	8	8	8	Bits		
Relative accuracy				±0.1			±0.1	%FS		
V _{CC+}	Positive supply voltage	11.4	15		11.4	15		V		
V _{CC-}	Negative supply voltage	-11.4	-15		-11.4	-15		V		
V _{IN(1)}	Logic "1" input voltage	Pin 1 = 0V			2.0			V		
V _{IN(0)}	Logic "0" input voltage	Pin 1 = 0V		0.8			0.8	V		
I _{IN(1)}	Logic "1" input current	Pin 1 = 0V, 2V < V _{IN} < 18V		0.1	10		0.1	10	μA	
I _{IN(0)}	Logic "0" input current	Pin 1 = 0V, -5V < V _{IN} < 0.8V		-2.0	-10		-2.0	-10	μA	
I _{FS}	Full scale output current	Unipolar operation V _{REF IN} = 5.000V, T _A = 25°C		1.90	1.992	2.10	1.90	1.992	2.10	mA
I _{ZS}	Zero scale current				1		1		μA	
V _{REF}	Reference voltage	I _{REF} = 1mA T _A = 25°C		4.9	5.0	5.25	4.9	5.0	5.25	V
PSR ⁺ (out)	Output power supply rejection (+)	V ₋ = -15V, 13.5V ≤ V ₊ ≤ 16.5V, external V _{REF IN} = 5.000V		.001	.01		.001	.01	%FS/ %VS	
PSR ⁻ (out)	Output power supply rejection (-)	V ₊ = 15V, -13.5V ≤ V ₋ ≤ -16.5V, external V _{REF IN} = 5.000V		.001	.01		.001	.01	%FS/ %VS	
TC _{FS}	Full scale temperature coefficient	V _{REF IN} = 5.000V ¹			20		20		ppm/°C	
TC _{ZS}	Zero scale temperature coefficient	I _{REF IN} = 1.00mA ²			5		5		ppm/°C	

NOTES

1. This is for voltage out only. See Unipolar Voltage Output schematic
2. This is for current output mode

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DC ELECTRICAL CHARACTERISTICS (Cont'd) $V_{CC+} = +15V$, $V_{CC-} = -15V$, SE5119, $-55^{\circ}C \leq T_A \leq 125^{\circ}C$,
NE5119, $0^{\circ}C \leq T_A \leq 70^{\circ}C$ unless otherwise specified.
Typical values are specified at $25^{\circ}C$

PARAMETER	TEST CONDITIONS	SE5119			NE5119			UNIT
		Min	Typ	Max	Min	Typ	Max	
I_{REF}	Reference output current	Note 1 $T_A = 25^{\circ}C$ $V_{REF OUT} = 0V$						mA
I_{REFSC}	Reference short circuit current		15	30		15	30	mA
PSR+(REF)	Reference power supply rejection (+)	$V- = -15V, 13.5V \leq V+ \leq 16.5V,$ $I_{REF} = 1.0mA$.003	.01		.003	.01	%VR / %VS
PSR-(REF)	Reference power supply rejection (-)	$V+ = 15V, -13.5V \leq V- \leq 16.5V,$ $I_{REF} = 1.0mA$.003	.01		.003	.01	%VR / %VS
TCREF	Reference voltage temperature coefficient	$I_{REF} = 1.0mA$		60		60		ppm/ $^{\circ}C$
Z_{IN}	DAC R_{REFIN} input impedance		5.0			5.0		k Ω
I_{CC+}	Positive supply current	$V_{CC+} = 15V$		7		7		mA
I_{CC-}	Negative supply current	$V_{CC-} = -15V$		-10		-10		mA
PD	Power dissipation	$I_{REF} = 1.0mA, V_{CC} = \pm 15V$		255		255		mW

AC ELECTRICAL CHARACTERISTICS $V_{CC} = \pm 15V, T_A = 25^{\circ}C$

PARAMETER	TO	FROM	TEST CONDITIONS	SE/NE5119			UNIT
				Min	Typ	Max	
T_{SLH}	Settling time	$\pm \frac{1}{2}$ LSB	Input	All bits Low-to-high			ns
T_{SHL}	Settling time	$\pm \frac{1}{2}$ LSB	Input	All bits High-to-low			ns
t_{PLH}	Propagation delay	Output	Input	All bits switched Low-to-high			ns
t_{PHL}	Propagation delay	Output	Input	All bits switched High-to-low			ns
t_{PLSB}	Propagation delay	Output	Input	1 LSB change			ns
t_{PLH}	Propagation delay	Output	\overline{LE}	Low-to-high transition			ns
t_{PHL}	Propagation delay	Output	\overline{LE}	High-to-low transition			ns
t_s	Set-up time	\overline{LE}	Input	100			ns
t_h	Hold time	Input	\overline{LE}	50			ns
t_{pw}	Latch enable pulse width			150			ns

NOTES

1. For reference currents > 3mA, use of an external buffer is required.

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